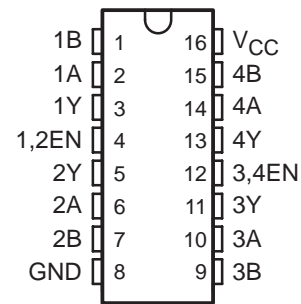


SN65LBC175A, SN75LBC175A QUADRUPLER RS-485 DIFFERENTIAL LINE RECEIVERS

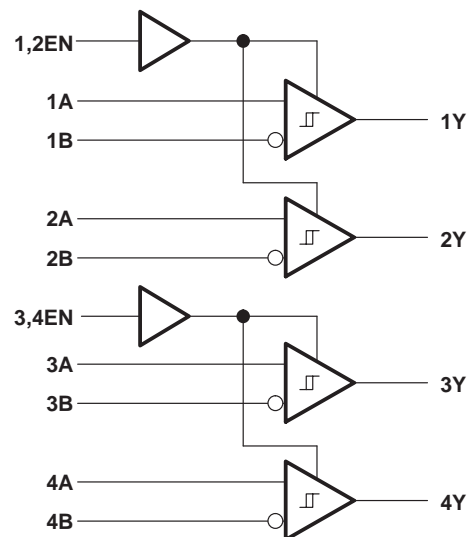
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- Designed for TIA/EIA-485, TIA/EIA-422, and ISO 8482 Applications
- Signaling Rate¹ Exceeding 50 Mbps
- Fail-Safe in Bus Short-Circuit, Open-Circuit, and Idle-Bus Conditions
- ESD Protection on Bus Inputs 6 kV
- Common-Mode Bus Input Range –7 V to 12 V
- Propagation Delay Times <16 ns
- Low Standby Power Consumption <20 μ A
- Pin-Compatible Upgrade for MC3486, DS96F175, LTC489, and SN75175

SN65LBC175A (Marked as 65LBC175A)
SN75LBC175A (Marked as 75LBC175A)
D or N PACKAGE
(TOP VIEW)



logic diagram



description

The SN65LBC175A and SN75LBC175A are quadruple differential line receivers with 3-state outputs, designed for TIA/EIA-485 (RS-485), TIA/EIA-422 (RS-422), and ISO 8482 (Euro RS-485) applications.

These devices are optimized for balanced multipoint bus communication at data rates up to and exceeding 50 million bits per second. The transmission media may be twisted-pair cables, printed-circuit board traces, or backplanes. The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media and the noise coupling to the environment.

Each receiver operates over a wide range of positive and negative common-mode input voltages, and features ESD protection to 6 kV, making it suitable for high-speed multipoint data transmission applications in harsh environments. These devices are designed using LinBiCMOS™, facilitating low power consumption and inherent robustness.

Two EN inputs provide pair-wise enable control, or these can be tied together externally to enable all four drivers with the same signal.

The SN75LBC175A is characterized for operation over the temperature range of 0°C to 70°C. The SN65LBC175A is characterized over the temperature range from –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinBiCMOS is a trademark of Texas Instruments.

¹The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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SN65LBC175A, SN75LBC175A QUADRUPLE RS-485 DIFFERENTIAL LINE RECEIVERS

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FUNCTION TABLE

(each receiver)

DIFFERENTIAL INPUTS A – B (V _{ID})	ENABLE EN	OUTPUT Y
V _{ID} ≤ -0.2 V	H	L
-0.2 V < V _{ID} < -0.01 V	H	?
-0.01 V ≤ V _{ID}	H	H
X	L	Z
X	OPEN	Z
Short circuit	H	H
Open circuit	H	H

H = high level, L = low level, X = irrelevant, Z = high impedance (off),
 ? = indeterminate

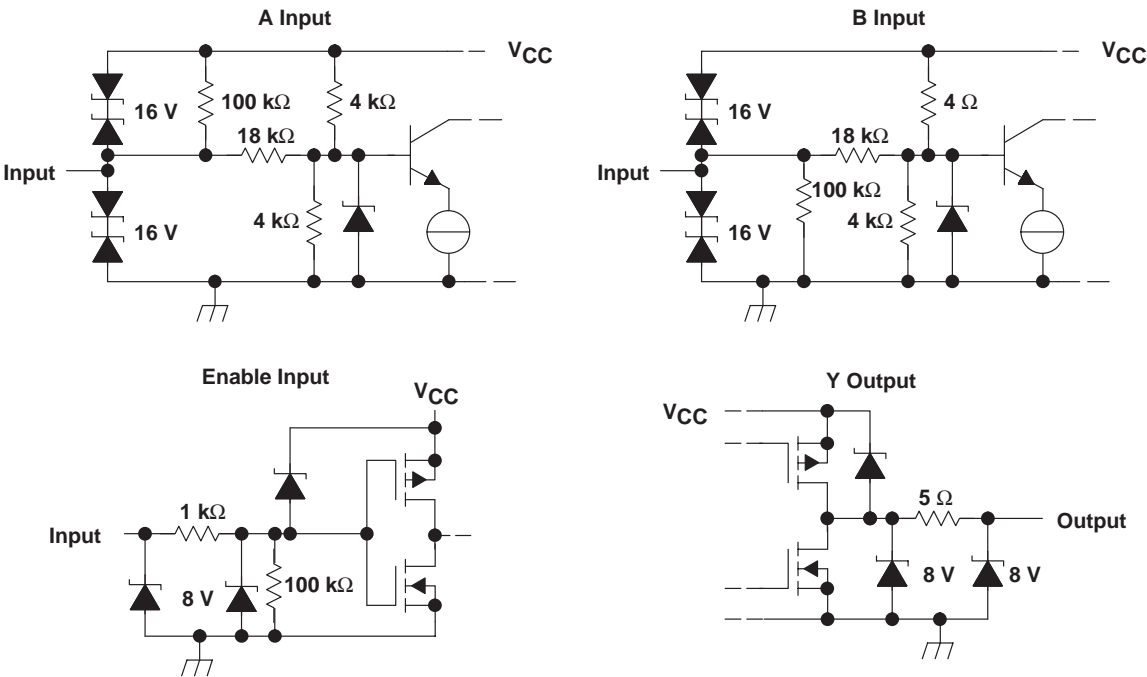
AVAILABLE OPTIONS

T _A	PACKAGE	
	PLASTIC SMALL OUTLINE† (JEDEC MS-012)	PLASTIC DUAL-IN-LINE (JEDEC MS-001)
0°C to 70°C	SN75LBC175AD	SN75LBC175AN
-40°C to 85°C	SN65LBC175AD	SN65LBC175AN

† Add an R suffix for taped and reeled

† For the most current package and ordering information, see the
 Package Option Addendum at the end of this document, or see the
 TI web site at www.ti.com.

equivalent input and output schematic diagrams



SN65LBC175A, SN75LBC175A QUADRUPLE RS-485 DIFFERENTIAL LINE RECEIVERS

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absolute maximum ratings[†] over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V_{CC} (see Note 1)	–0.3 V to 6 V
Voltage range at any bus input (steady state), A and B	–10 V to 15 V
Voltage range at any bus input (transient pulse through 100 Ω , see Figure 5)	–30 V to 30 V
Voltage input range at 1,2EN and 3,4EN, V_I	–0.5 V to $V_{CC} + 0.5$ V
Receiver output current, I_O	± 10 mA
Electrostatic discharge:	
Human body model (see Note 2): A and B to GND	6 kV
All pins	5 kV
Charged-device model (see Note 3): All pins	2 kV
Continuous power dissipation	See Power Dissipation Rating Table

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to GND, and are steady-state (unless otherwise specified).
2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.
3. Tested in accordance with JEDEC Standard 22, Test Method C101.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR [†] ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
D	1080 mW	8.7 mW/ $^\circ\text{C}$	690 mW	560 mW
N	1150 mW	9.2 mW/ $^\circ\text{C}$	736 mW	598 mW

[†] This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.75	5	5.25	V
Voltage at any bus terminal	A, B	–7		12	V
High-level input voltage, V_{IH}	EN	2	V_{CC}	0.8	V
Low-level input voltage, V_{IL}		0			
Output current	Y	–8		8	mA
Operating free-air temperature, T_A	SN75LBC175A	0		70	$^\circ\text{C}$
	SN65LBC175A	–40		85	



SN65LBC175A, SN75LBC175A

QUADRUPLE RS-485 DIFFERENTIAL LINE RECEIVERS

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electrical characteristics over recommended operating conditions

PARAMETER			TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V _{IT+}	Positive-going differential input voltage threshold		−7 V ≤ V _{CM} ≤ 12 V (V _{CM} = (V _A + V _B) / 2)		−80	−10	mV	
V _{IT−}	Negative-going differential input voltage threshold				−200	−120		
V _{HYS}	Hysteresis voltage (V _{IT+} − V _{IT−})				−40		mV	
V _{IK}	Input clamp voltage		I _I = −18 mA		−1.5	−0.8	V	
V _{OH}	High-level output voltage		V _{ID} = 200 mV, I _{OH} = −8 mA	See Figure 1	2.7	4.8	V	
V _{OL}	Low-level output voltage		V _{ID} = −200 mV, I _{OL} = 8 mA		0.2	0.4		
I _{OZ}	High-impedance-state output current		V _O = 0 V to V _{CC}		−1		1	μA
I _I	Line input current		Other input at 0 V, V _{CC} = 0 V or 5 V	V _I = 12 V	0.9		mA	
				V _I = −7 V	−0.7			
I _{IH}	High-level input current	Enable inputs				100	μA	
I _{IL}	Low-level input current					−100	μA	
R _I	Input resistance		A, B		12		kΩ	
I _{CC}	Supply current		V _{ID} = 5 V	1,2EN, 3,4EN at 0 V	20		mA	
			No load	1,2EN, 3,4EN at V _{CC}	11 16		mA	

† All typical values are at $V_{CC} = 5\text{ V}$ and 25°C .

switching characteristics over recommended operating conditions

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_r	Output rise time	$V_{ID} = -3\text{ V to } 3\text{ V}$, See Figure 2		2	4	ns
t_f	Output fall time			2	4	ns
t_{PLH}	Propagation delay time, low-to-high level output		9	12	16	ns
t_{PHL}	Propagation delay time, high-to-low level output		9	12	16	ns
t_{PZH}	Propagation delay time, high-impedance to high-level output	See Figure 3		27	38	ns
t_{PHZ}	Propagation delay time, high-level to high-impedance output			7	16	ns
t_{PZL}	Propagation delay time, high-impedance to low level output	See Figure 4		29	38	ns
t_{PLZ}	Propagation delay time, low-level to high-impedance output			12	16	ns
$t_{sk(p)}$	Pulse skew ($ t_{PLH} - t_{PHL} $)			0.2	1	ns
$t_{sk(o)}$	Output skew (see Note 4)				2	ns
$t_{sk(pp)}$	Part-to-part skew (see Note 5)				2	ns

† All typical values are at $V_{CC} = 5\text{ V}$ and 25°C .

NOTES: 4. Outputs skew ($t_{sk(o)}$) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together.

5. Part-to-part skew ($t_{sk(pp)}$) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.

PARAMETER MEASUREMENT INFORMATION

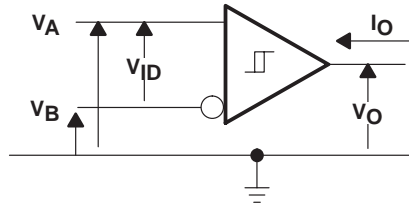


Figure 1. Voltage and Current Definitions

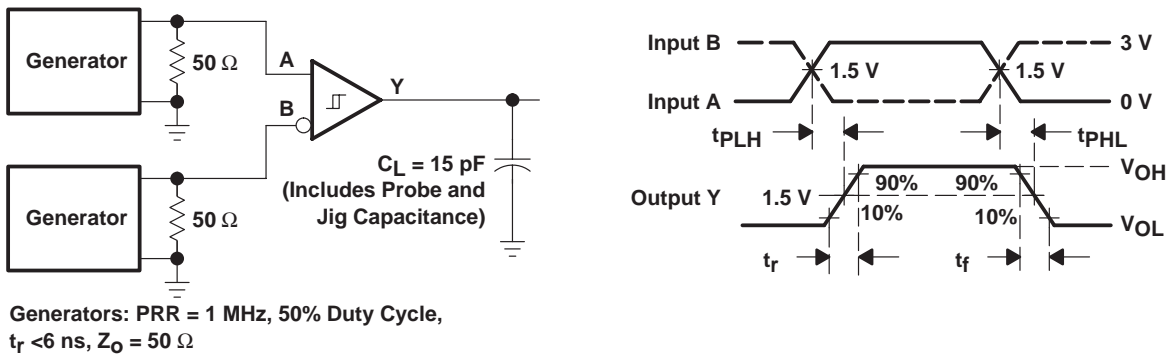


Figure 2. Switching Test Circuit and Waveforms

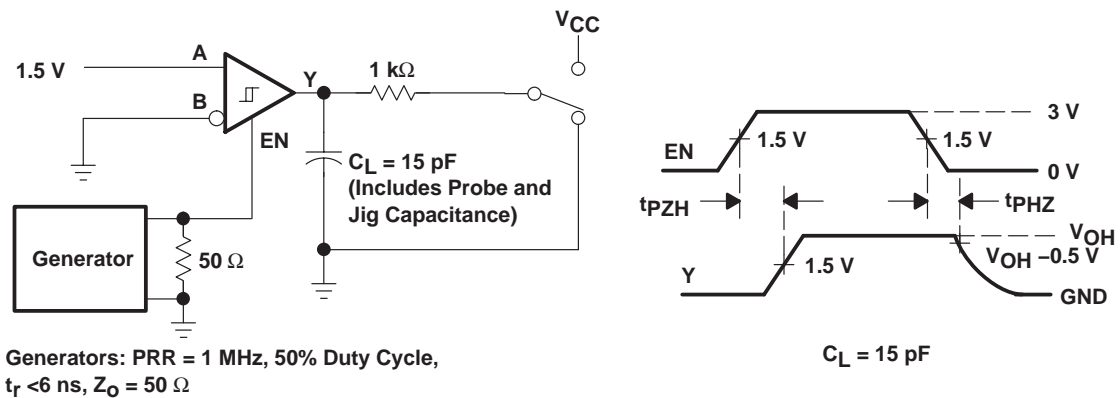


Figure 3. Test Circuit Waveforms, t_{PZH} and t_{PHZ}

SN65LBC175A, SN75LBC175A QUADRUPLE RS-485 DIFFERENTIAL LINE RECEIVERS

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PARAMETER MEASUREMENT INFORMATION

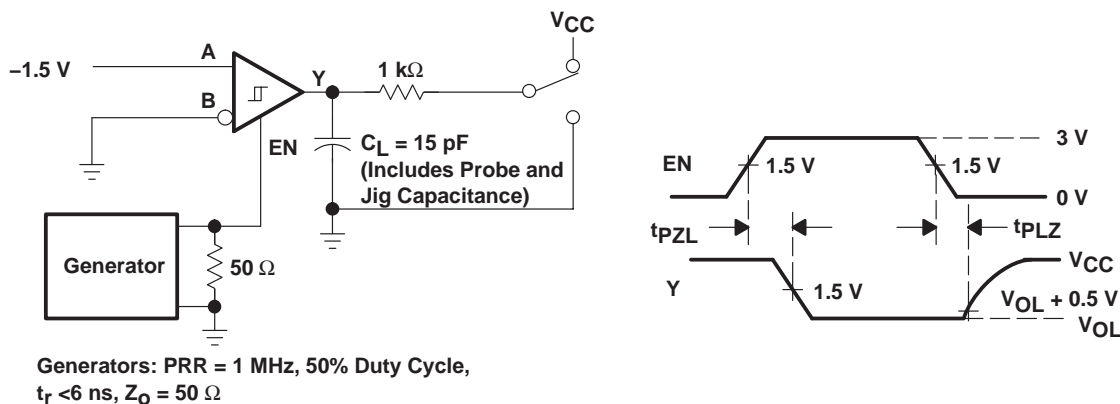


Figure 4. Test Circuit Waveforms, t_{PZL} and t_{PLZ}

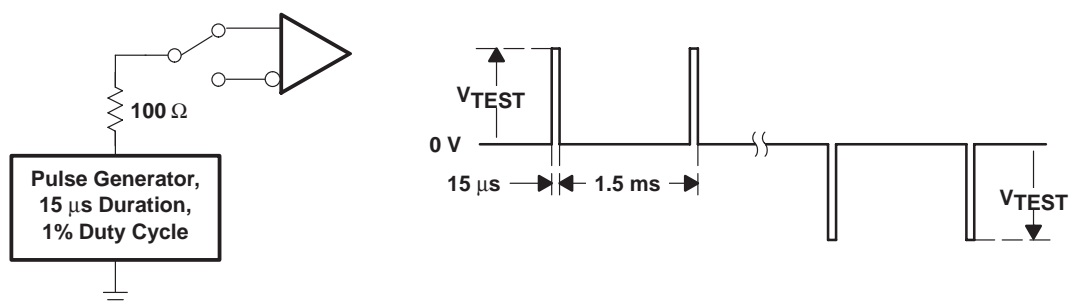


Figure 5. Test Circuit and Waveform, Transient Over-Voltage Test

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TYPICAL CHARACTERISTICS

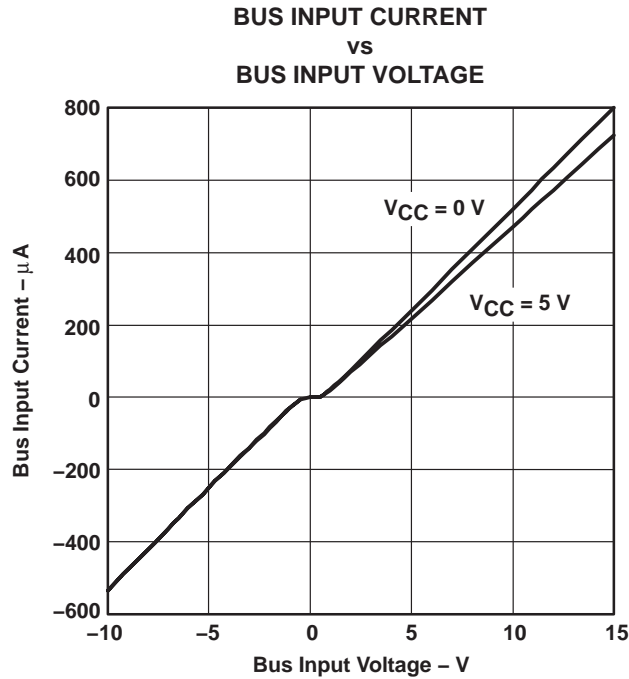


Figure 6

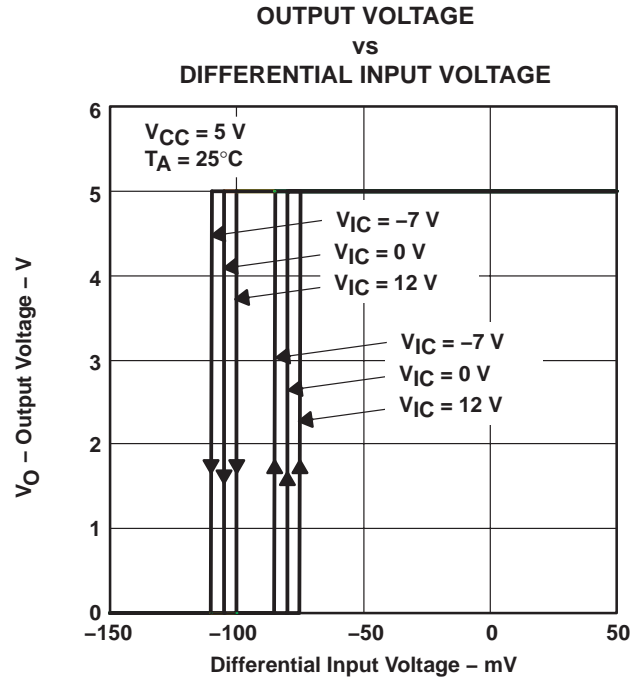


Figure 7

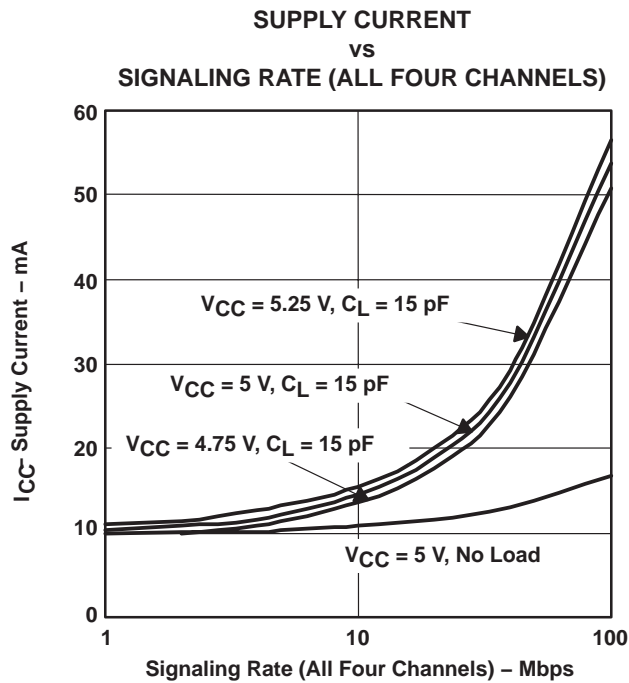


Figure 8

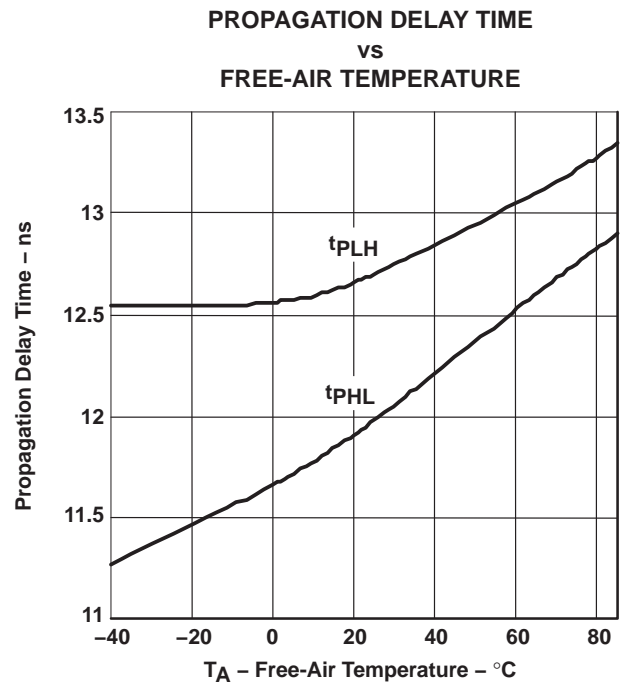


Figure 9

SN65LBC175A, SN75LBC175A QUADRUPLE RS-485 DIFFERENTIAL LINE RECEIVERS

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TYPICAL CHARACTERISTICS

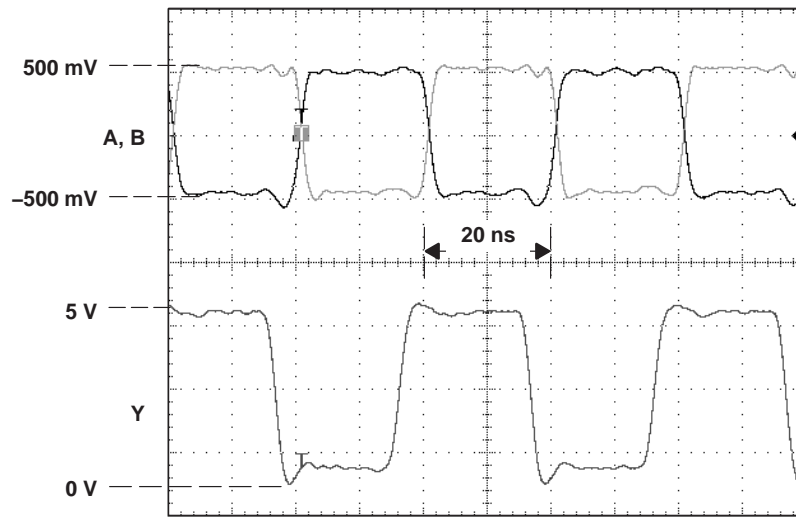


Figure 10. Receiver Inputs and Outputs, 50 Mbps Signaling Rate

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APPLICATION INFORMATION

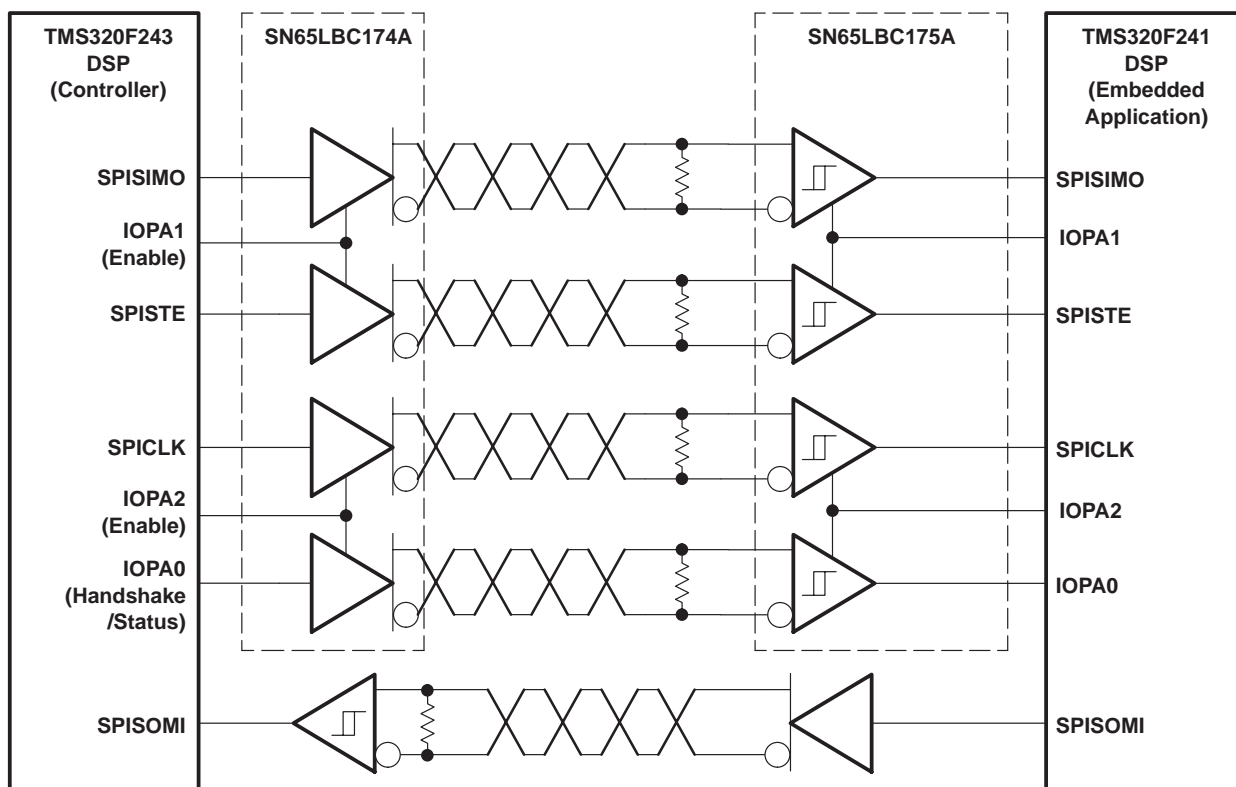


Figure 11. Typical Application Circuit, DSP-to-DSP Link via Serial Peripheral Interface

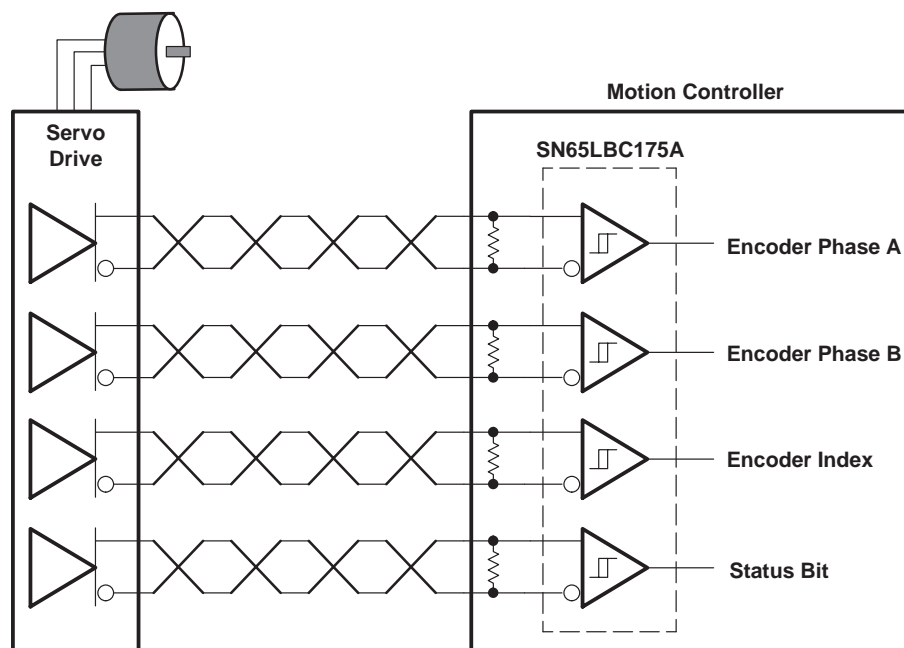


Figure 12. Typical Application Circuit, High-Speed Servomotor Encoder Interface

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65LBC175AD	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC175A	Samples
SN65LBC175ADG4	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC175A	Samples
SN65LBC175ADR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC175A	Samples
SN65LBC175AN	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	65LBC175A	Samples
SN75LBC175AD	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75LBC175A	Samples
SN75LBC175ADR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75LBC175A	Samples
SN75LBC175AN	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	75LBC175A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN65LBC175A :

- Enhanced Product: [SN65LBC175A-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC175ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75LBC175ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC175ADR	SOIC	D	16	2500	333.2	345.9	28.6
SN75LBC175ADR	SOIC	D	16	2500	333.2	345.9	28.6

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4211283-4/E 08/12

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.

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